Academic Rules and Regulations PVP19

## PVP-19

<b>RF CIRCUIT DESIGN</b>							
Course Code	19EC4605D	Year	III	Semester	II		
Course Category	Program Elective-III	Branch	ECE	Course Type	Theory		
Credits	3	L-T-P	3-0-0	Prerequisites	Electronic Devices and Amplifier Circuits (19EC3305)		
Continuous Internal Evaluation	30	Semester End Evaluation	70	Total Marks	100		

	Course Outcomes							
Upon	successful completion of the course, the student will be able to							
CO1	Interpret the properties of active and passive components at high frequency							
	applications (L2)							
CO2	Develop transmission lines used in RF circuit design (L3).							
<b>CO3</b>	Build independent and interconnected networks (L3).							
<b>CO4</b>	Analyze characteristics of transistor amplifiers for RF applications (L4)							

Ma	pping	g of co	ourse	outco	mes v	with <b>F</b>	Progra	am ou	itcom	es (CC	<b>)/ PO/</b>	PSO N	latrix)	)
Note: 1- Weak correlation						2-Medium correlation 3-Strong correlation								
* - Average value indicates course correlation strength with mapped PO														
COs	PO1	PO2	PO3	PO4	PO5	PO6	<b>PO7</b>	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	2	2	2	2	1								1	2
CO2	3	2	3	2	2								2	3
CO3	2	3	3	2	3								2	3
CO4	2	3	3	3	2								3	3
Average*														
(Rounded	2	2	2	2	2								2	2
to nearest	2	5	3	2	2								2	3
integer)														

	Syllabus				
Unit No.	Contents	Mapped CO			
Ι	<b>Introduction:</b> Importance of Radio Frequency Design, Dimensions and Units, frequency Spectrum. RF behavior of Passive Components- Resistors, Capacitors and Inductors at high frequency. Chip Components and Circuit Board Considerations-Chip Resistors, Chip Capacitors, Surface-Mounted inductors. RF circuit Manufacturing Processes	CO1			

## **PVP-19**

П	Active RF Components: Semiconductor Basics – Physical Properties of Semiconductors, the PN-Junction, Schottky Contact. RF Diodes-Schottky Diode, PIN Diode, Varactor Diode, Tunnel Diode. Bipolar-Junction Transistor - Construction, Functionality and Frequency Response. RF Field Effect Transistors - Construction, Functionality, Frequency Response. Metal Oxide Semiconductor Transistors-Construction, Functionality	CO1
III	<b>Transmission Line Analysis:</b> Examples of Transmission Lines – Two- Wire Lines, Coaxial Line, Microstrip Lines. Equivalent Circuit Representation, basic laws, Circuit parameters for a Parallel –Plate Transmission Line. General Transmission line equation, characteristic impedance, lossless transmission line model, Microstrip Transmission lines	CO2
IV	<b>Single and Multiport Networks:</b> Basic definitions, interconnecting networks-series and parallel connection of networks, Cascading networks, ABCD network representation. Network properties and applications-inter relations between parameter sets. Scattering Parameters-Definition of S-parameters, chain scattering matrix	CO3
V	<b>RF Transistor Amplifier Design:</b> Characteristics of Amplifiers – Amplifier Matching Basics, Power amplifiers, Broadband Amplifiers, High Power Amplifiers, multistage amplifiers.	CO4
	Learning Resources	
Text ]	Books	
1. Rl Pe 2. Se	F Circuit Design: Theory and applications by Reinhold Ludwing and Gene arson Education Asia Publication, New Delhi 2001 crets of RF Design by Joseph Carr., 3 <sup>rd</sup> Edition, Tata McGraw-Hill Formany Limited.	Bogdnov Publishing
Refer	ence Books	
Refer   1. Ra	ence Books idio frequency and microwave electronic illustrated Mathew M. Radmane	esh, 2001,
Refer 1. Ra Pe	ence Books dio frequency and microwave electronic illustrated Mathew M. Radmane arson Education.	esh, 2001,
Refer   1. Ra   Pe Pe   e- Res 1.	ence Books adio frequency and microwave electronic illustrated Mathew M. Radmane arson Education. sources & other digital material <u>https://nptel.ac.in/courses/117/102/117102012/#</u>	esh, 2001,